

Product Summary

BV _{DSS}	R _{DS(on)}	I _D T _A = +25°C
-60V	125mΩ @ V _{GS} = -10V	-4.3A
	190mΩ @ V _{GS} = -4.5V	-3.5A

Description and Applications

This MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor control
- DC-DC converters
- Power-management functions
- Uninterruptible power supplies

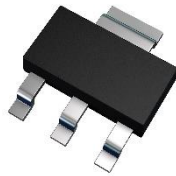
Features and Benefits

- Fast Switching Speed
- Low Gate Drive
- Low Input Capacitance
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
<https://www.diodes.com/quality/product-definitions/>
- An automotive-compliant part is available under a separate datasheet ([ZXMP6A17GQ](#))

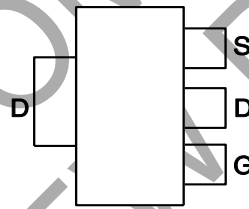
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

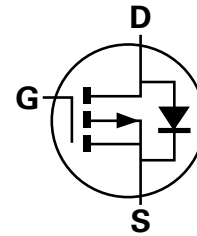
SOT223 (Type DN)



Top View



Pin Out - Top View



Equivalent Circuit

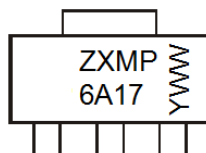
Ordering Information (Note 4)

Orderable Part Number	Package	Packing	
		Qty.	Carrier
ZXMP6A17GTA	SOT223 (Type DN)	1,000	Tape & Reel
ZXMP6A17GTC	SOT223 (Type DN)	4,000	Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

SOT223 (Type DN)



ZXMP6A17 = Product Type Marking Code
YWW = Date Code Marking
Y or Y = Year (ex: 6 = 2026)
WW or WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

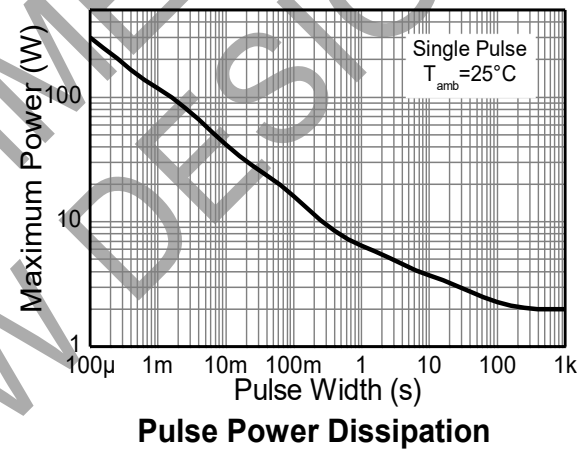
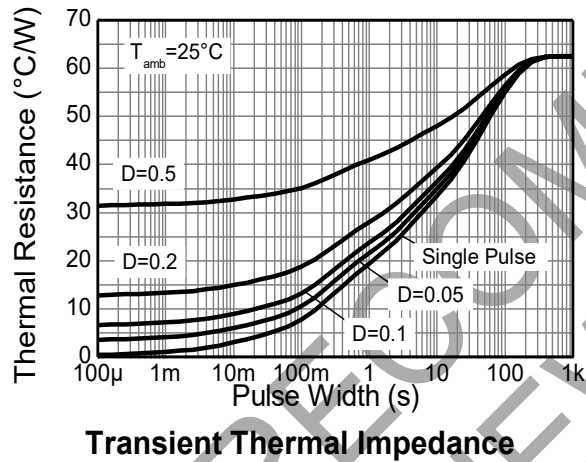
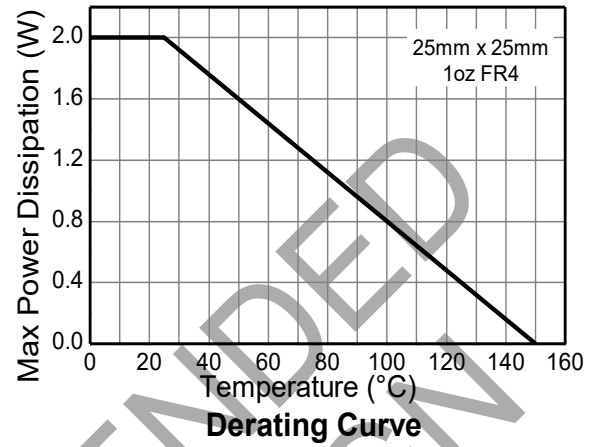
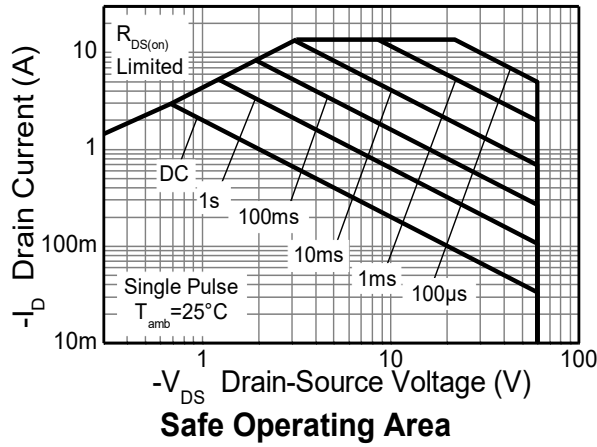
Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current	V _{GS} = 10V	(Note 6)	I _D	-4.3	A
		T _A = +70°C (Note 6)		-3.5	
		(Note 5)		-3.0	
Pulsed Drain Current	V _{GS} = 10V	(Note 7)	I _{DM}	-13.7	A
Continuous Source Current (Body Diode)			I _S	-4.3	A
Pulsed Source Current (Body Diode)			I _{SM}	-13.7	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P _D	2.0	W
	(Note 6)		16	
Linear Derating Factor	(Note 5)	R _{θJA}	3.9	mW/°C
	(Note 6)		31	
Thermal Resistance, Junction to Ambient	(Note 5)	R _{θJA}	62.5	°C/W
	(Note 6)		32.0	
Thermal Resistance, Junction to Lead	(Note 8)	R _{θJL}	9.8	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

- Notes:
- For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 - Same as Note 5, except the device is measured at t ≤ 10sec.
 - Same as Note 5, except the device is pulsed with D = 0.02 and pulse width 300μs. The pulse current is limited by the maximum junction temperature.
 - Thermal resistance from junction to solder-point (at the end of the drain lead).

Thermal Characteristics



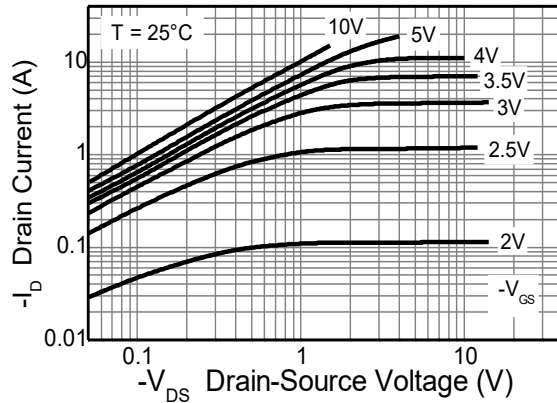
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	-60	—	—	V	I _D = -250μA, V _{GS} = 0	
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-0.5	μA	V _{DS} = -60V, V _{GS} = 0	
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±20V, V _{DS} = 0	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	-1.0	—	—	V	I _D = -250μA, V _{DS} = V _{GS}	
Static Drain-Source On-Resistance (Note 9)	R _{DS(ON)}	—	96	125	mΩ	V _{GS} = -10V, I _D = -2.2A	
			120	190		V _{GS} = -4.5V, I _D = -1.8A	
Forward Transconductance (Notes 9 & 10)	g _{fs}	—	4.7	—	S	V _{DS} = -15V, I _D = -2.2A	
Diode Forward Voltage (Note 9)	V _{SD}	—	-0.85	-0.95	V	I _S = -2.0A, V _{GS} = 0, T _J = +25°C	
Reverse Recovery Time (Note 10)	t _{rr}	—	25.1	—	ns	I _S = -1.7A, di/dt = 100A/μs, T _J = +25°C	
Reverse Recovery Charge (Note 10)	Q _{rr}	—	27.2	—	nC		
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	—	637	—	pF	V _{DS} = -30V, V _{GS} = 0 f = 1MHz	
Output Capacitance	C _{oss}	—	70.0	—	pF		
Reverse Transfer Capacitance	C _{rss}	—	53.0	—	pF		
Total Gate Charge (Note 11)	Q _g	—	9.0	—	nC	V _{GS} = -4.5V	V _{DS} = -30V I _D = -2.2A
Total Gate Charge (Note 11)	Q _g	—	17.7	—	nC	V _{GS} = -10V	
Gate-Source Charge (Note 11)	Q _{gs}	—	1.6	—	nC		
Gate-Drain Charge (Note 11)	Q _{gd}	—	4.4	—	nC		
Turn-On Delay Time (Note 11)	t _{D(on)}	—	2.6	—	ns	V _{DD} = -30V, V _{GS} = -10V I _D = -1A, R _G ≅ 6.0Ω	
Turn-On Rise Time (Note 11)	t _r	—	3.4	—	ns		
Turn-Off Delay Time (Note 11)	t _{D(off)}	—	26.2	—	ns		
Turn-Off Fall Time (Note 11)	t _f	—	11.3	—	ns		

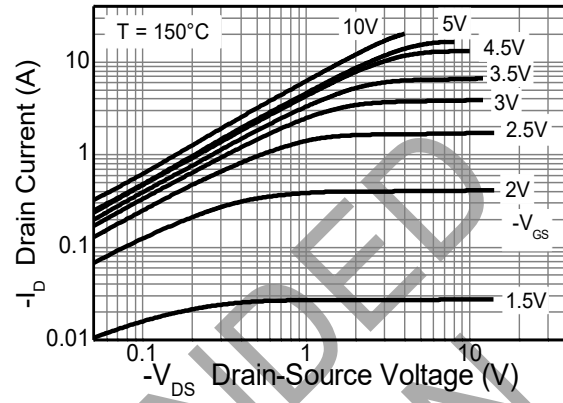
Notes:

9. Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%.
10. For design aid only, not subject to production testing.
11. Switching characteristics are independent of operating junction temperatures.

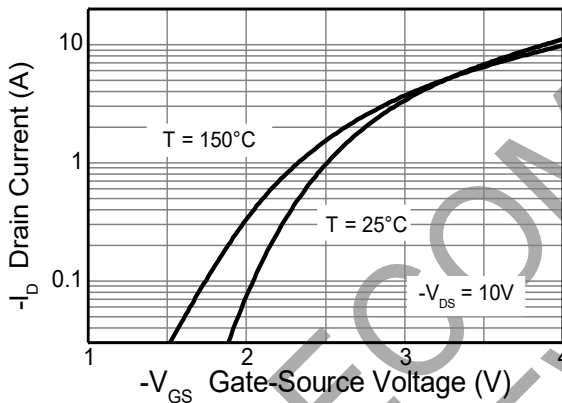
Typical Characteristics



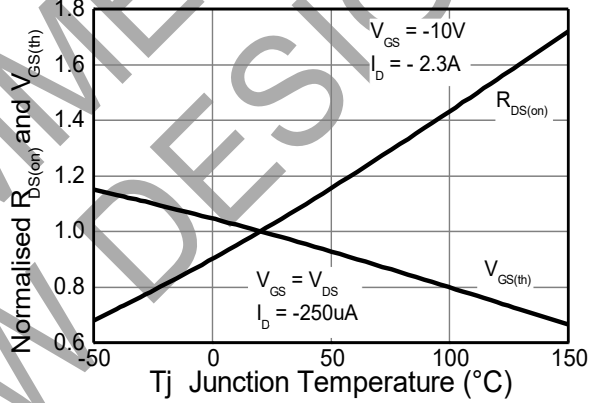
Output Characteristics



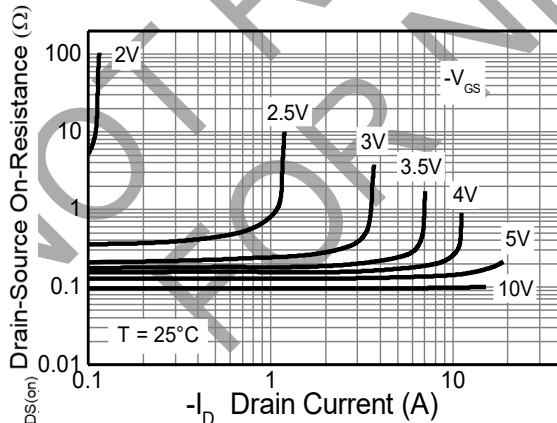
Output Characteristics



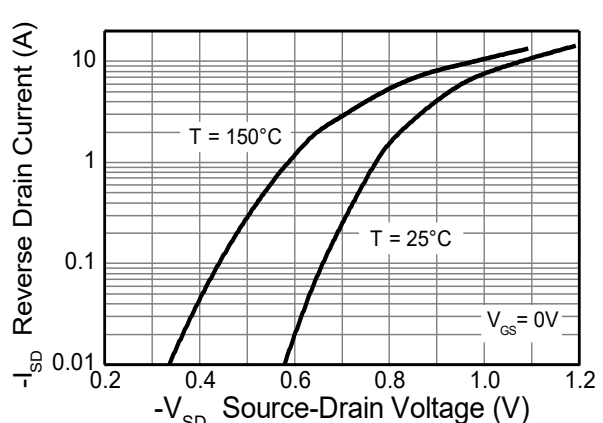
Typical Transfer Characteristics



Normalised Curves v Temperature

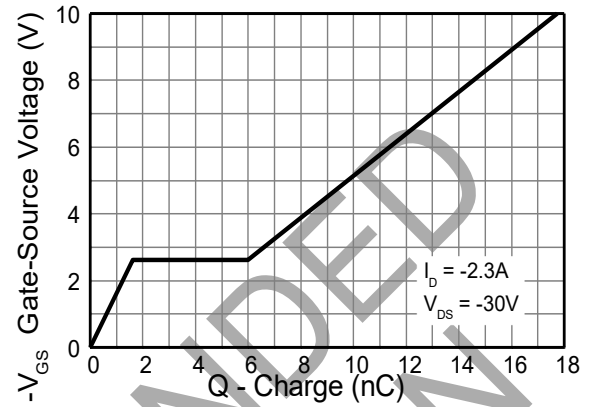
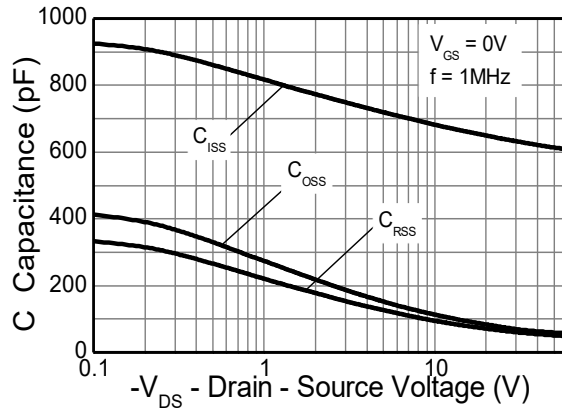


On-Resistance v Drain Current

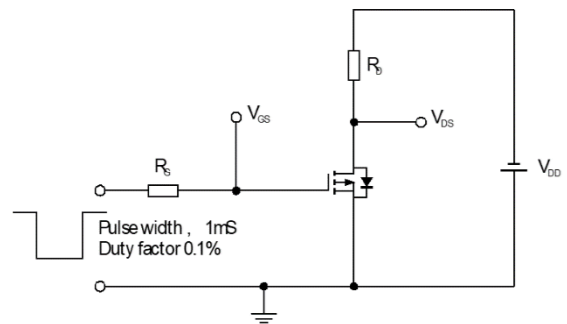
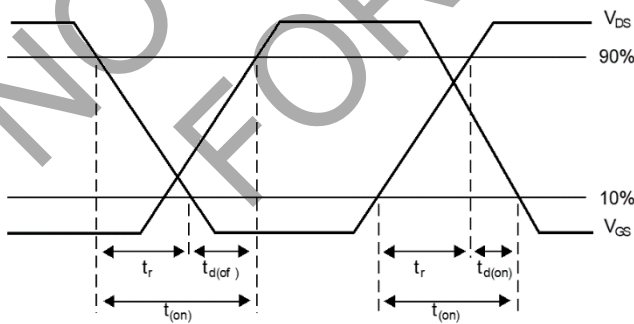
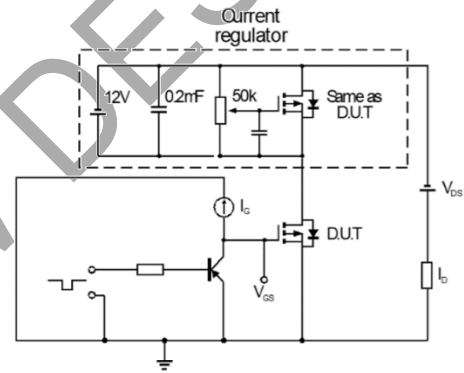
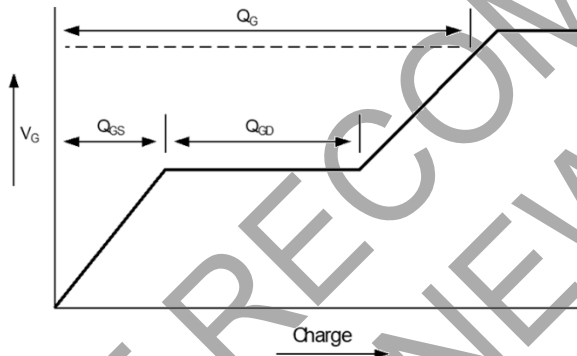


Source-Drain Diode Forward Voltage

Typical Characteristics (continued)



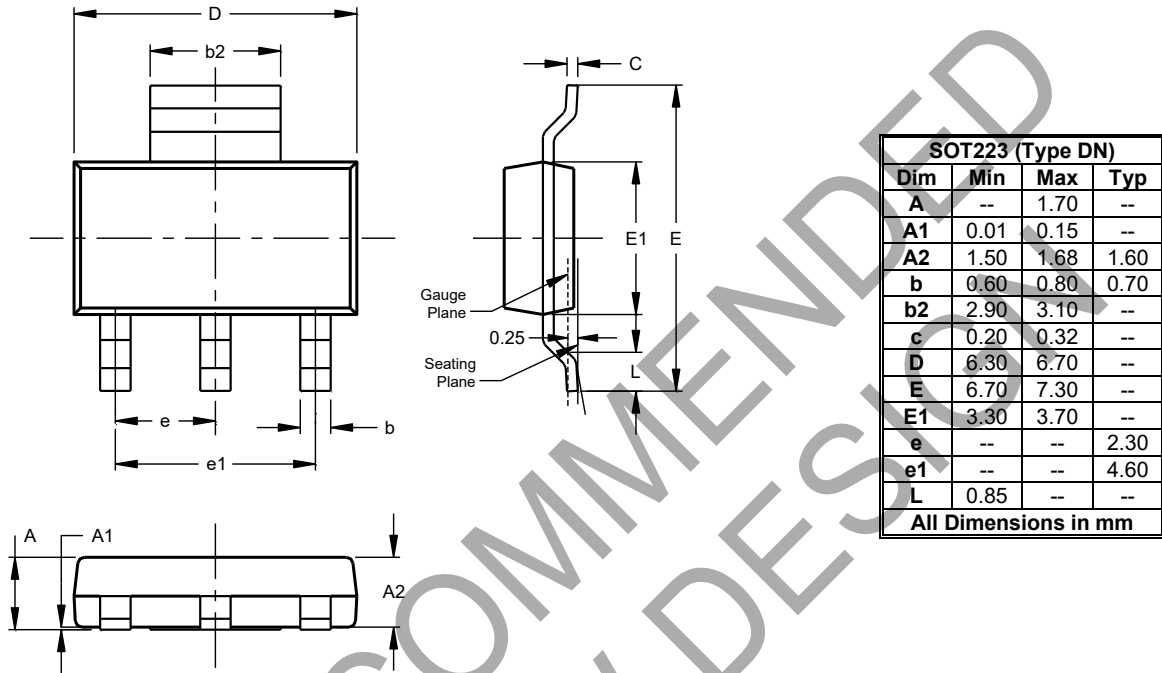
Test Circuits



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

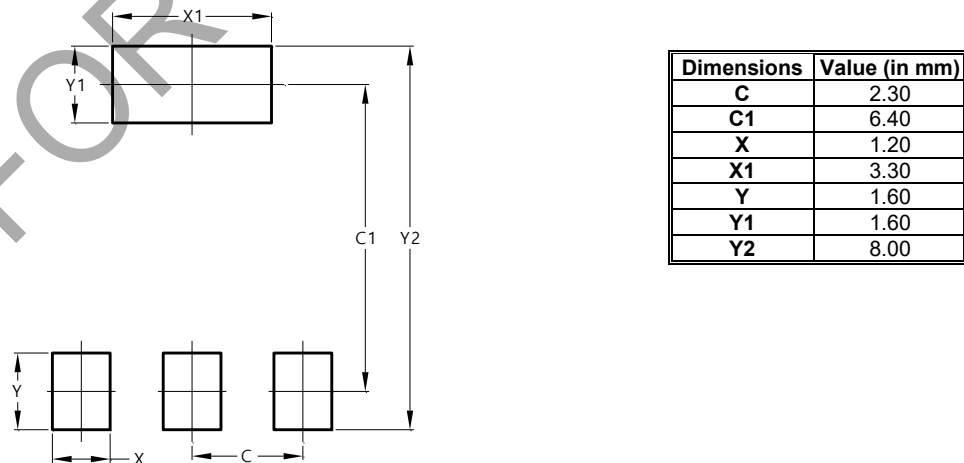
SOT223 (Type DN)



Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



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